



SMT GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 21 - 29 GHz

Typical Applications

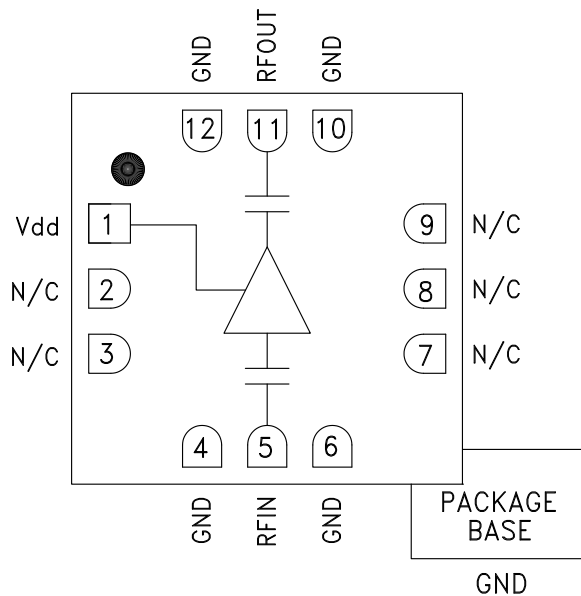
The HMC341LC3B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military End-Use

Features

- 2.5 dB Noise Figure
- 13 dB Gain
- +3V @ 35 mA Supply
- 50 Ohm Matched Input/Output
- RoHS Compliant 3x3 mm SMT Package

Functional Diagram



General Description

The HMC341LC3B is a GaAs pHEMT MMIC Low Noise Amplifier housed in a leadless RoHS compliant SMT package. Operating from 21 to 29 GHz, the amplifier provides 13 dB of gain and a noise figure of 2.5 dB from a single +3V supply. The RF I/Os are DC blocked and matched to 50 Ohms requiring no external components. The HMC341LC3B eliminates the need for wire bonding, allowing the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = +3\text{V}$, $I_{dd} = 35\text{mA}$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	21 - 24			24 - 26			26 - 29			GHz
Gain	10.5	13.5		10	13		9	12		dB
Gain Variation Over Temperature		0.016	0.025		0.016	0.025		0.016	0.025	dB/°C
Noise Figure		3.25	5		3	3.5		2.5	3	dB
Input Return Loss		10			11			9		dB
Output Return Loss		14			10			9		dB
Output Power for 1 dB Compression (P1dB)		8			8.5			8.5		dBm
Saturated Output Power (Psat)		11			11.5			11.5		dBm
Output Third Order Intercept (IP3)		19			19			19		dBm
Supply Current (Idd) (Vdd = +3V)		35			35			35		mA

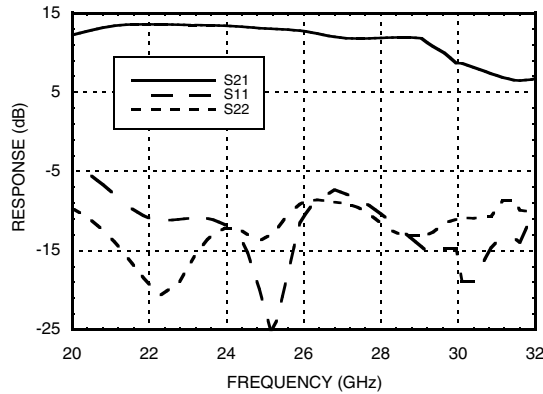
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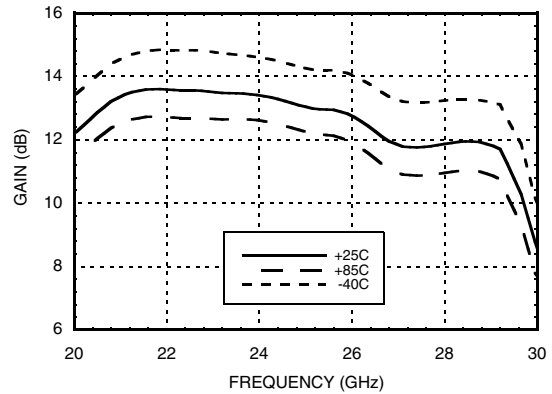


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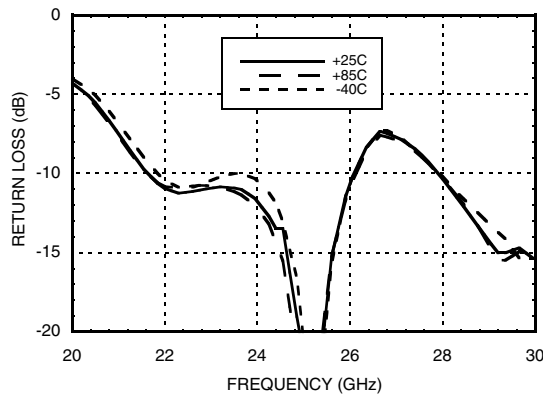
Broadband Gain & Return Loss



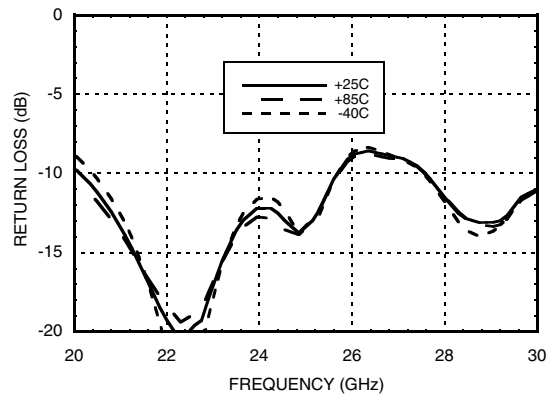
Gain vs. Temperature



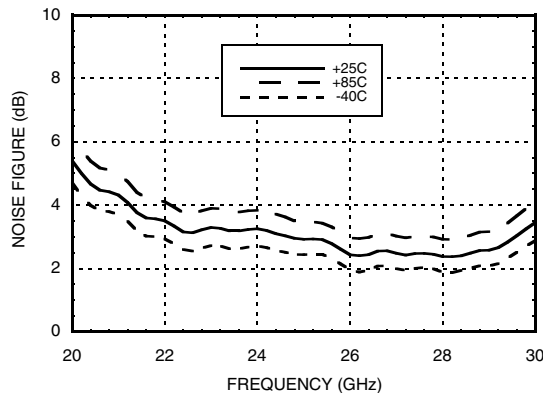
Input Return Loss vs. Temperature



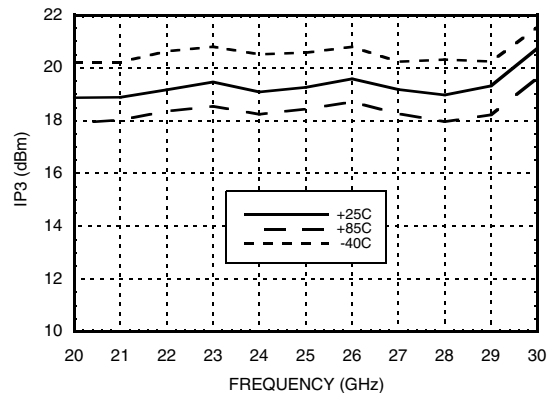
Output Return Loss vs. Temperature



Noise Figure vs. Temperature



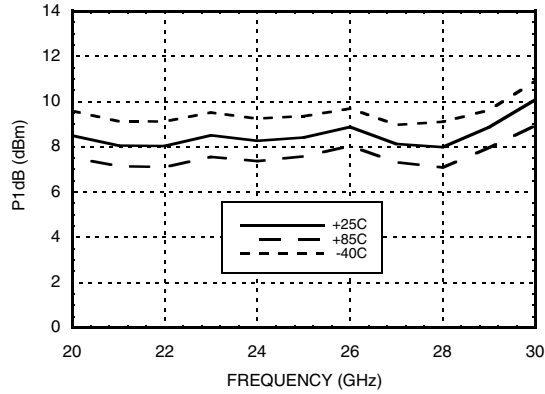
Output IP3 vs. Temperature



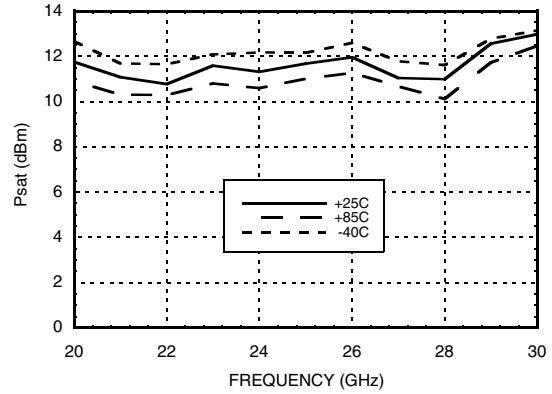


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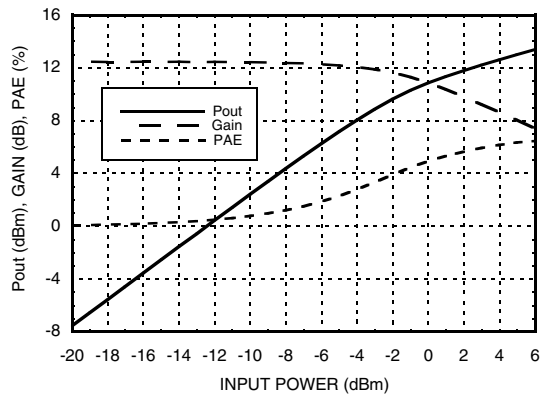
P1dB vs. Temperature



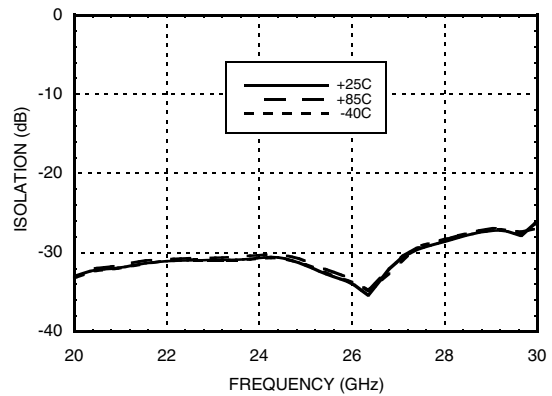
Psat vs. Temperature



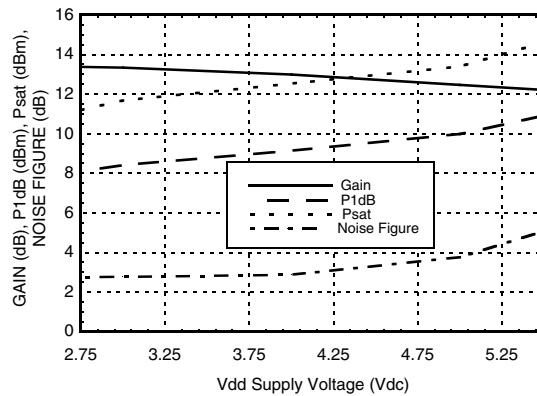
Power Compression @ 25 GHz



Reverse Isolation vs. Temperature



Gain, Power & Noise Figure vs. Supply Voltage @ 25 GHz



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Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+5.5 Vdc
RF Input Power (RFIN)(Vdd = +3.0 Vdc)	+5 dBm
Channel Temperature	175 °C
Continuous P _{diss} (T= 85 °C) (derate 5.43 mW/°C above 85 °C)	0.489 W
Thermal Resistance (channel to ground paddle)	184 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd

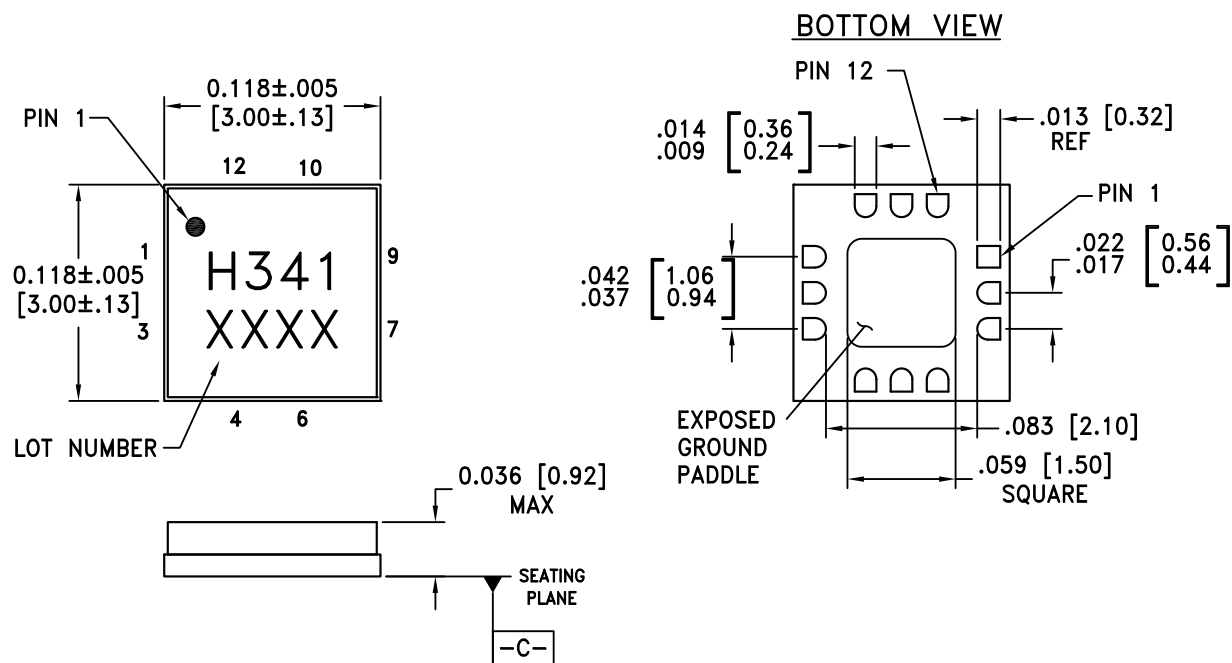
Vdd (Vdc)	I _{dd} (mA)
+2.7	34
+3.0	35
+4.0	38
+5.0	41

Note: Amplifier will operate over full voltage ranges shown above.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA.
2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER NICKEL.
3. DIMENSIONS ARE IN INCHES (MILLIMETERS).
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM $\square-C$.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC341LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H341 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vdd	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1000pF, and 2.2 μF are required.	
2, 3, 7-9	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
4, 6, 10, 12	GND	Package bottom has an exposed metal paddle that must also be connected to RF/DC ground.	
5	RFIN	This pin is AC coupled and matched to 50 Ohms from 21 - 29 GHz.	
11	RFOUT	This pin is AC coupled and matched to 50 Ohms from 21 - 29 GHz.	

Application Circuit

Component	Value
C1	100 pF
C2	1,000 pF
C3	2.2 μF

